

# Slotted Optical Switch

OPB852A1-3

OPB853A1-3



## Features:

- Inexpensive opaque plastic housing
- Choice of transistor (OPB852) or photodarlington (OPB853) output
- 0.125" (3.18 mm) slot width
- 0.290" (7.37 mm) lead spacing
- Apertured for high resolution



## Description:

Slotted optical switches in the OPB852, and OPB853 series consist of an infrared emitting diode and a NPN silicon phototransistor or photodarlington, mounted on opposite sides of a 0.125" (3.175 mm) wide slot. The OPB852A, OPB852B and OPB852C have phototransistor output, while the OPB853A, OPB853B and OPB853C have photodarlington output.

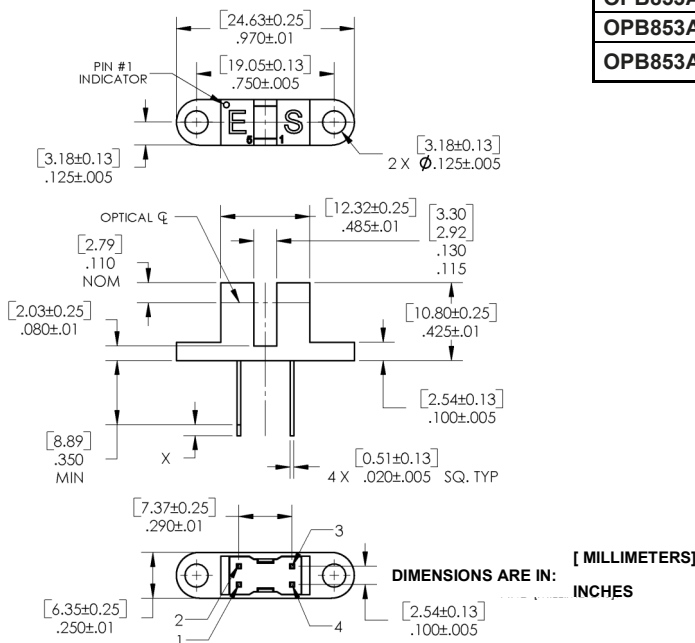
On each of these devices, the emitter has a molded-in aperture of 0.050" x 0.050" (1.270 mm x 1.270 mm) and the phototransistor (OPB852) or photodarlington (OPB853) has a molded-in aperture of 0.010" x 0.050" (0.254 mm x 1.270 mm).

Phototransistor or photodarlington switching occurs when an opaque object passes through the slot.

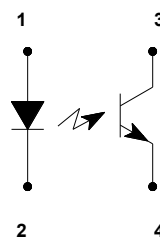
## Applications:

- Non-contact interruptive object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety

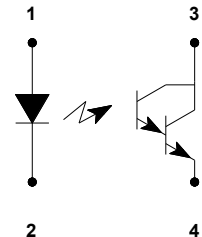
Part Number	LED Peak Wavelength	Sensor	Slot Width/Depth	Aperture Emitter/Sensor	Lead Length / Spacing
OPB852A1	890 nm	Transistor	0.120" / 0.315"	0.05" / 0.01"	0.425" / 0.290"
OPB852A2					
OPB852A3					
OPB853A1		Darlington			
OPB853A2					
OPB853A3					



OPB852



OPB853



Pin #	Description
1	Anode
2	Cathode
3	Collector
4	Emitter



RoHS

## General Note

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## Electrical Specifications

**Absolute Maximum Ratings** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Storage & Operating Temperature Range	-40°C to +85°C
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron]	260°C <sup>(1)</sup>

### Input Diode

Forward DC Current	40 mA
Peak Forward Current (1 $\mu\text{s}$ pulse width, 300 pps)	3 A
Reverse DC Voltage	2 V
Power Dissipation	100 mW <sup>(2)</sup>

### Output Phototransistor

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	100 mW <sup>(2)</sup>

**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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**Input Diode** (see OP140 for additional information—OPB852A\_, OP245 for additional information—OPB853A)

$V_F$	Forward Voltage	-	-	1.7	V	$I_F = 20\text{ mA}$
$I_R$	Reverse Current	-	-	100	$\mu\text{A}$	$V_R = 2\text{ V}$

**Output Phototransistor** (see OP550 for additional information—OPB852A\_, OP565 for additional information—OPB853A)

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_C = 1\text{ mA}$
	OPB852A1, OPB852A2, OPB852A3 OPB853A1, OPB853A2, OPB853A3	15	-	-	V	$I_C = 1\text{ mA}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_E = 100\ \mu\text{A}$
$I_{CEO}$	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10\text{ V}$

### Combined

$V_{CE(SAT)}$	Saturation Voltage	-	-	-	V	$I_C = 500\ \mu\text{A}, I_F = 20\text{ mA}$
	OPB852A1, OPB852A2	-	-	0.4	V	$I_C = 1.8\text{ mA}, I_F = 20\text{ mA}$
	OPB852A3 OPB853A1, OPB853A2, OPB853A3	-	-	1.0	V	$I_C = 1.8\text{ mA}, I_F = 10\text{ mA}$
$I_{C(ON)}$	On-State Collector Current	-	-	-	mA	$V_{CE} = 5\text{ V}, I_F = 20\text{ mA}$
	OPB852A1	1.0	-	-	mA	$V_{CE} = 5\text{ V}, I_F = 20\text{ mA}$
	OPB852A2	2.0	-	-	mA	$V_{CE} = 5\text{ V}, I_F = 20\text{ mA}$
	OPB852A3	4.0	-	-	mA	$V_{CE} = 5\text{ V}, I_F = 20\text{ mA}$
	OPB853A1	2.5	-	-	mA	$V_{CE} = 1.5\text{ V}, I_F = 5\text{ mA}$
	OPB853A2 OPB853A3	5.0 10.0	- -	- -	mA mA	$V_{CE} = 1.5\text{ V}, I_F = 5\text{ mA}$ $V_{CE} = 1.5\text{ V}, I_F = 5\text{ mA}$

Notes:

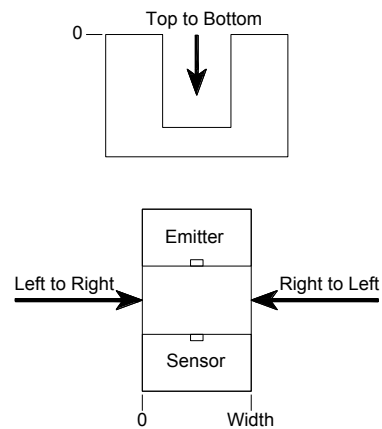
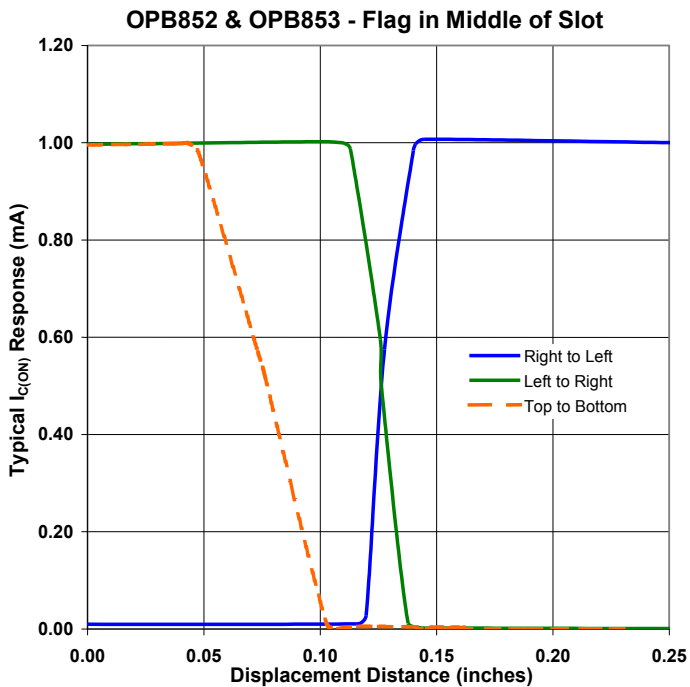
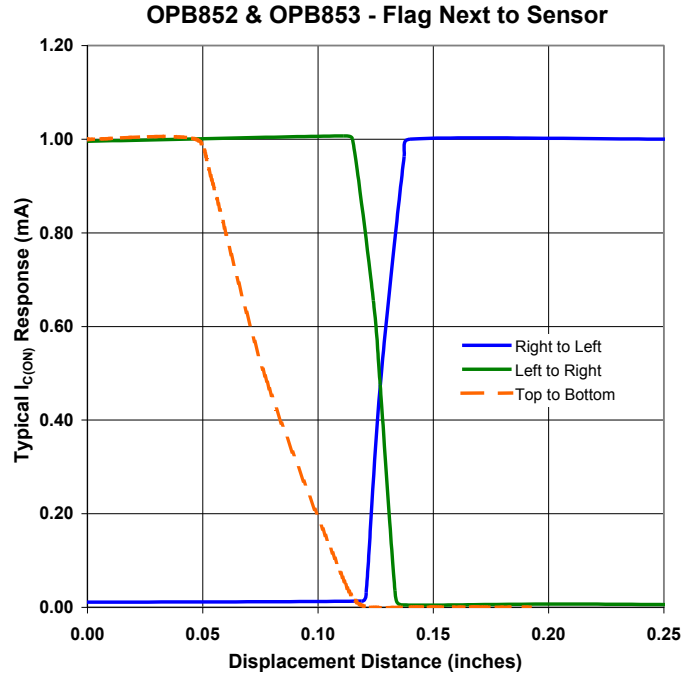
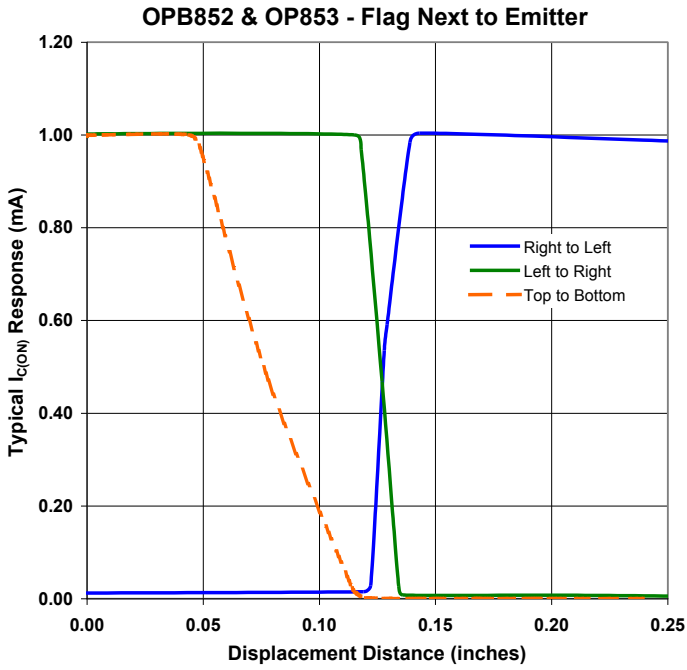
- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.67 mW/ $^\circ\text{C}$  above 25°C.
- (3) Methanol and isopropanol are recommended as cleaning agents. Housings are soluble in chlorinated hydrocarbons and ketones. Highly activated, water soluble fluxes may attack housings in some situations.
- (4) All parameters tested using pulse technique.

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## Performance



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